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November 2013

FDP20N50 / FDPF20N50 / FDPF20N50T

N-Channel UniFETTM MOSFET 500 V, 20 A, 230 m Ω

Features

- $R_{DS(on)}$ = 200 m Ω (Typ.) @ V_{GS} = 10 V, I_D = 10 A
- Low Gate Charge (Typ. 45.6 nC)
- Low C_{rss} (Typ. 27 pF)
- · 100% Avalanche Tested

Applications

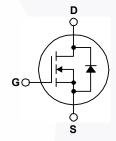
- LCD/LED/PDP TV
- Lighting
- · Uninterruptible Power Supply
- · AC-DC Power Supply

Description

UniFETTM MOSFET is Fairchild Semiconductor's high voltage MOSFET family based on planar stripe and DMOS technology. This MOSFET is tailored to reduce on-state resistance, and to provide better switching performance and higher avalanche energy strength. This device family is suitable for switching power converter applications such as power factor correction (PFC), flat panel display (FPD) TV power, ATX and electronic lamp ballasts.







Absolute Maximum Ratings T_C = 25°C unless otherwise noted.

| Symbol | Parameter | | FDP20N50 FDPF20N | | Unit |
|----------------------------------|--|----------|------------------|----------------|--------|
| V_{DSS} | V _{DSS} Drain-Source Voltage | | 500 | | |
| I _D | Drain Current - Continuous ($T_C = 25^{\circ}C$ - Continuous ($T_C = 100^{\circ}$ | | 20 12.9 | 20 * 12.9 * | A A |
| I _{DM} | Drain Current - Pulsed | (Note 1) | 80 | 80 * | Α |
| V _{GSS} | Gate-Source voltage | | ±30 | | V |
| E _{AS} | Single Pulsed Avalanche Energy (Note 2) | | 1110 | | mJ |
| I _{AR} | Avalanche Current (Note 1) | | 20 | | Α |
| E _{AR} | Repetitive Avalanche Energy (Note 1) | | 25 | | mJ |
| dv/dt | Peak Diode Recovery dv/dt (Note 3) | | 4.5 | | V/ns |
| P _D | Power Dissipation (T _C = 25°C) - Derate above 25°C | | 250 2.0 | 38.5 0.3 | W/°C |
| T _{J,} T _{STG} | Operating and Storage Temperature Range | | -55 to +150 | | °C |
| TL | Maximum Lead Temperature for Soldering, 1/8" from Case for 5 Seconds | | 300 | | |

^{*} Drain current limited by maximum junction temperature.

Thermal Characteristics

| Symbol | Parameter | FDP20N50 | FDPF20N50/ FDPF20N50T | Unit |
|-----------------|---|----------|--------------------------|------|
| $R_{\theta JC}$ | Thermal Resistance, Junction-to-Case, Max. | 0.5 | 3.3 | °C/W |
| $R_{\theta JA}$ | Thermal Resistance, Junction-to-Ambient, Max. | 62.5 | 62.5 | C/VV |

Package Marking and Ordering Information

| Part Number | Top Mark | Package | Packing Method | Reel Size | Tape Width | Quantity |
|-------------|-----------|---------|----------------|-----------|------------|----------|
| FDP20N50 | FDP20N50 | TO-220 | Tube | N/A | N/A | 50 units |
| FDPF20N50 | FDPF20N50 | TO-220F | Tube | N/A | N/A | 50 units |
| FDPF20N50T | FDPF20N50 | TO-220F | Tube | N/A | N/A | 50 units |

Electrical Characteristics $T_C = 25^{\circ}C$ unless otherwise noted.

| Symbol | Parameter | Conditions | Min. | Тур. | Max. | Unit |
|---|---|---|------|------|-------------|----------|
| Off Charac | Off Characteristics | | | | | |
| BV _{DSS} | Drain-Source Breakdown Voltage | $V_{GS} = 0 \text{ V, } I_D = 250 \mu\text{A}$ | 500 | | | V |
| ΔBV _{DSS} / ΔT _J | Breakdown Voltage Temperature Coefficient | I _D = 250 μA, Referenced to 25°C | | 0.5 | | V/°C |
| I _{DSS} | Zero Gate Voltage Drain Current | V _{DS} = 500 V, V _{GS} = 0 V V _{DS} = 400 V, T _C = 125°C | | | 1 10 | μA μA |
| I _{GSSF} | Gate-Body Leakage Current, Forward | V _{GS} = 30 V, V _{DS} = 0 V | | | 100 | nA |
| I _{GSSR} | Gate-Body Leakage Current, Reverse | V _{GS} = -30 V, V _{DS} = 0 V | | | -100 | nA |
| On Charac | teristics | | | | | • |
| V _{GS(th)} | Gate Threshold Voltage | $V_{DS} = V_{GS}, I_{D} = 250 \mu A$ | 3.0 | | 5.0 | V |
| R _{DS(on)} | Static Drain-Source On-Resistance | V _{GS} = 10 V, I _D = 10 A | | 0.20 | 0.23 | Ω |
| 9 _{FS} | Forward Transconductance | V _{DS} = 40 V, I _D = 10 A | - | 24.6 | | S |
| Dynamic C | Characteristics | | | | | |
| C _{iss} | Input Capacitance | V _{DS} = 25 V, V _{GS} = 0 V, | | 2400 | 3120 | pF |
| C _{oss} | Output Capacitance | f = 1.0 MHz | - | 355 | 465 | pF |
| C _{rss} | Reverse Transfer Capacitance | | | 27 | | pF |
| Switching | Characteristics | | | | | |
| t _{d(on)} | Turn-On Delay Time | V _{DD} = 250 V, I _D = 20 A, | | 95 | 200 | ns |
| t _r | Turn-On Rise Time | V_{GS} = 10 V, R_G = 25 Ω | | 375 | 760 | ns |
| t _{d(off)} | Turn-Off Delay Time | | | 100 | 210 | ns |
| t _f | Turn-Off Fall Time | (Note 4) | | 105 | 220 | ns |
| Q_g | Total Gate Charge | V _{DS} = 400 V, I _D = 20 A, | - | 45.6 | 59.5 | nC |
| Q _{gs} | Gate-Source Charge | V _{GS} = 10 V | / | 14.8 | | nC |
| Q _{gd} | Gate-Drain Charge | (Note 4) | - | 21.6 | | nC |
| Drain-Sou | rce Diode Characteristics and Maximur | n Ratings | | | | |
| I _S | Maximum Continuous Drain-Source Diode Forward Current | | | | 20 | Α |
| I _{SM} | Maximum Pulsed Drain-Source Diode Forward Current | | | | 80 | Α |
| V_{SD} | Drain-Source Diode Forward Voltage | V _{GS} = 0 V, I _S = 20 A | - | | 1.4 | V |
| t _{rr} | Reverse Recovery Time | V _{GS} = 0 V, I _S = 20 A, | | 507 | /- - | ns |
| Q _{rr} | Reverse Recovery Charge | dI _F /dt =100 A/μs | | 7.20 | | μС |

Notes:

- 1. Repetitive rating: pulse-width limited by maximum junction temperature.
- 2. L = 5.0 mH, I $_{AS}$ = 20 A, V $_{DD}$ = 50 V, R $_{G}$ = 25 $\Omega,$ starting T $_{J}$ = 25 $^{\circ}C.$
- 3. I $_{SD}$ \leq 20 A, di/dt \leq 200 A/µs, V $_{DD}$ \leq BV $_{DSS}$, starting T $_{J}$ = 25°C.
- 4. Essentially independent of operating temperature typical characteristics.

Typical Performance Characteristics

Figure 1. On-Region Characteristics

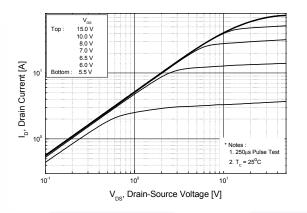


Figure 2. Transfer Characteristics

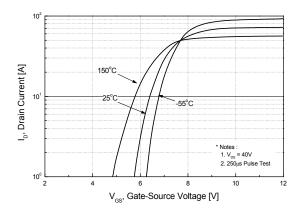
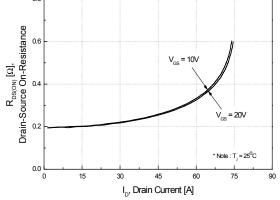


Figure 3. On-Resistance Variation vs.
Drain Current and Gate Voltage





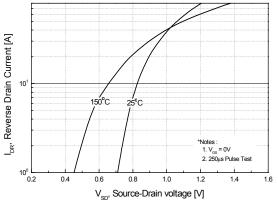


Figure 5. Capacitance Characteristics

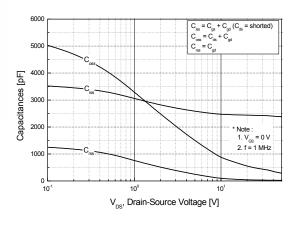
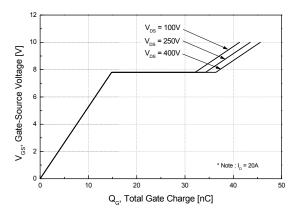


Figure 6. Gate Charge Characteristics



Typical Performance Characteristics (Continued)

Figure 7. Breakdown Voltage Variation vs. Temperature

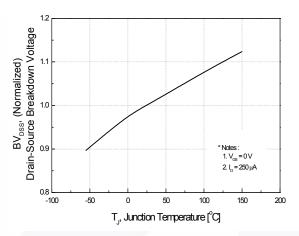


Figure 8. On-Resistance Variation vs. Temperature

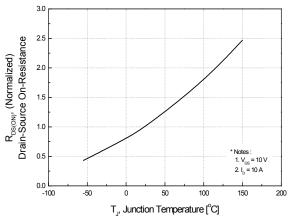
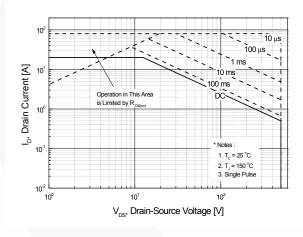


Figure 9-1. Maximum Safe Operating Area - FDP20N50

Figure 9-2. Maximum Safe Operating Area - FDPF20N50



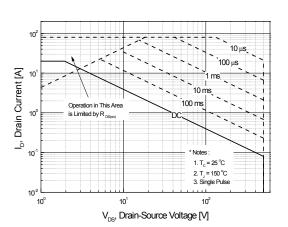
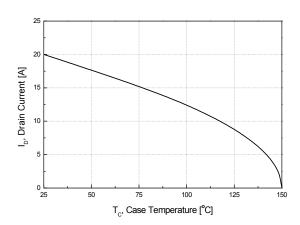


Figure 10. Maximum Drain Current vs. Case Temperature



Typical Performance Characteristics (Continued)

Figure 11-1. Transient Thermal Response Curve - FDP20N50

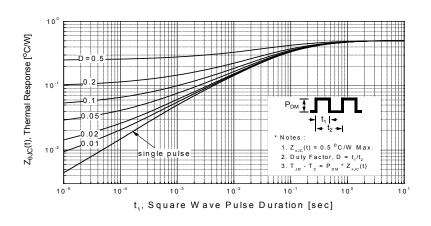
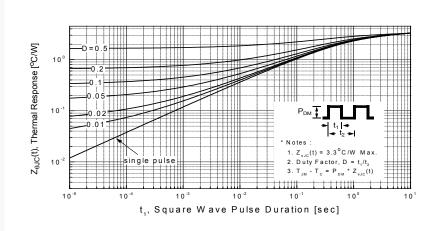


Figure 11-2. Transient Thermal Response Curve - FDPF20N50



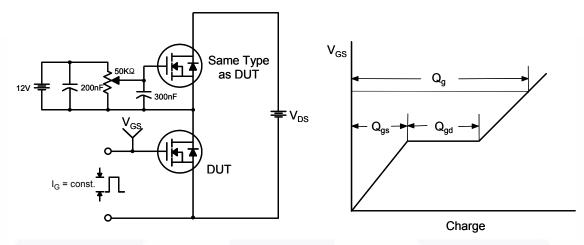


Figure 12. Gate Charge Test Circuit & Waveform

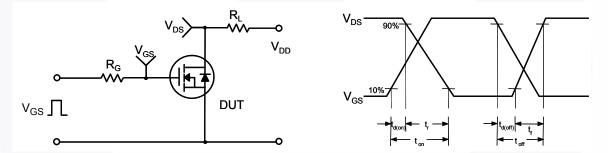


Figure 13. Resistive Switching Test Circuit & Waveforms

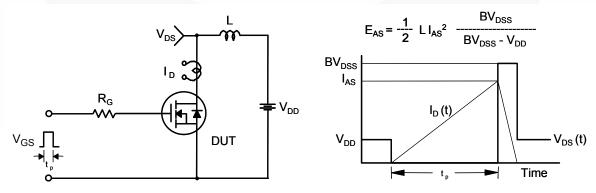


Figure 14. Unclamped Inductive Switching Test Circuit & Waveforms

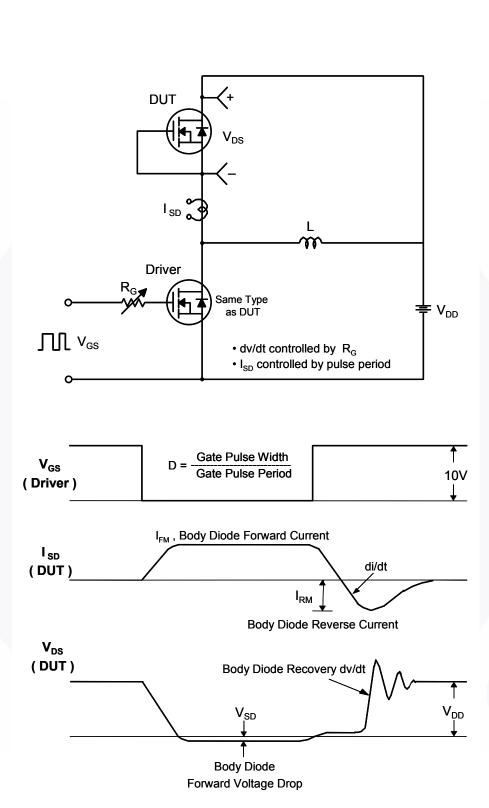


Figure 15. Peak Diode Recovery dv/dt Test Circuit & Waveforms

Mechanical Dimensions

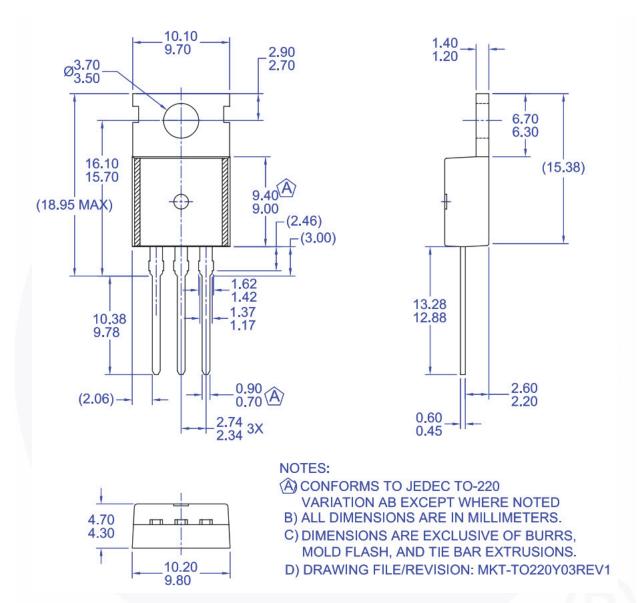


Figure 16. TO220, Molded, 3-Lead, Jedec Variation AB

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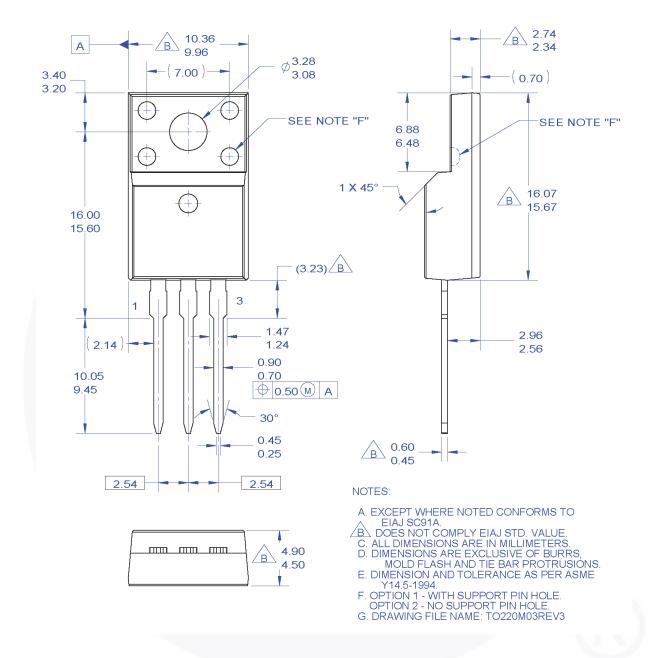


Figure 17. TO220, Molded, 3-Lead, Full Pack, EIAJ SC91, Straight Lead

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